



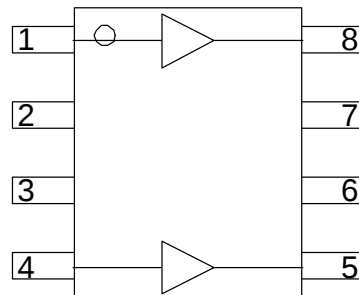
Product Description

RFMD's CGR-0218Z is a high performance InGaP HBT MMIC Amplifier designed with the InGaP process technology for excellent reliability. A Darlington configuration is utilized for broadband performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. The CGR-0218Z contains two amplifiers for use in wideband push-pull CATV amplifiers requiring excellent second order performance. The second and third order non-linearities are greatly improved in the push-pull configuration.

Optimum Technology Matching® Applied

- ☐ GaAs HBT
- ☐ GaAs MESFET
- ☒ InGaP HBT
- ☐ SiGe BiCMOS
- ☐ Si BiCMOS
- ☐ SiGe HBT
- ☐ GaAs pHEMT
- ☐ Si CMOS
- ☐ Si BJT
- ☐ GaN HEMT
- ☐ InP HBT
- ☐ RF MEMS
- ☐ LDMOS

Amplifier Configuration



Features

- 5V Single Supply
- Excellent Linearity
- Two Amplifiers in Each SOIC-8 Package Simplify Push-Pull PC Board Layout
- SOIC-8 Package
- Available in Lead-Free, RoHS Compliant Packaging

Applications

- CATV Head Ends
- CATV Line Drivers
- DOCSIS Cable Modems

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Small Signal Gain		17.3		dB	5MHz to 210MHz
Gain Flatness		±0.2		dB	5MHz to 210MHz
OIP ₃		42		dBm	5MHz to 210MHz, Tone Spacing=1MHz, P _{OUT} per tone=+6dBm
P1dB		23		dBm	5MHz to 210MHz
Input Return Loss		22		dB	5MHz to 210MHz
Output Return Loss		22		dB	5MHz to 210MHz
Noise Figure, Balun Insertion Loss Included		4.0		dB	5MHz to 210MHz
CSO		80		dBc	7 Ch, Flat Tilt, +50dBmV
CTB		67		dBc	7 Ch, Flat Tilt, +50dBmV
XMOD		66		dBc	7 Ch, Flat Tilt, +50dBmV
Device Operating Voltage		5.0		V	
Device Operating Current		217		mA	5V V _{CC}
Thermal Resistance (Junction to Lead)		30		°C/W	Junction to case slug

Test Conditions: V_{CC}=5V, I_D=217mA Typ., T_L=25°C, Z_S=Z_L=75Ω, Push Pull Application Circuit

Absolute Maximum Ratings

Parameter	Rating	Unit
Max Device Current (I_D)	300	mA
Max Device Voltage (V_D)	6.0	V
Max RF Input Power	18	dBm
Max Junction Temp (T_J)	150	°C
Operating Temp Range (T_L)	-40 to +85	°C
Max Storage Temp	150	°C
Min Storage Temp	-40	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH, j-l} \text{ and } T_L = T_{LEAD}$$

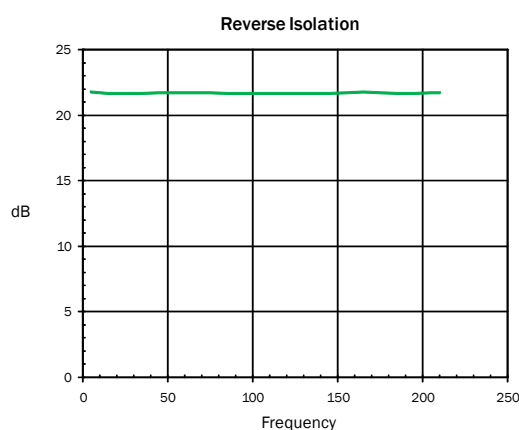
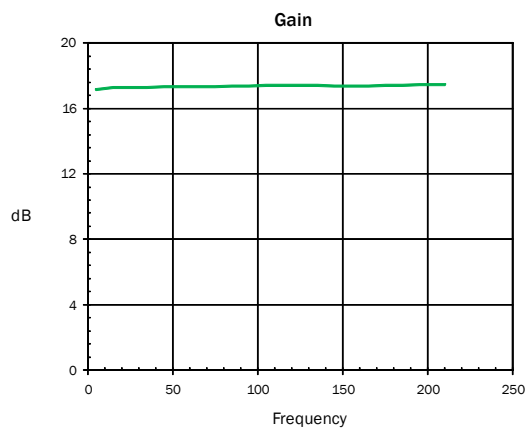
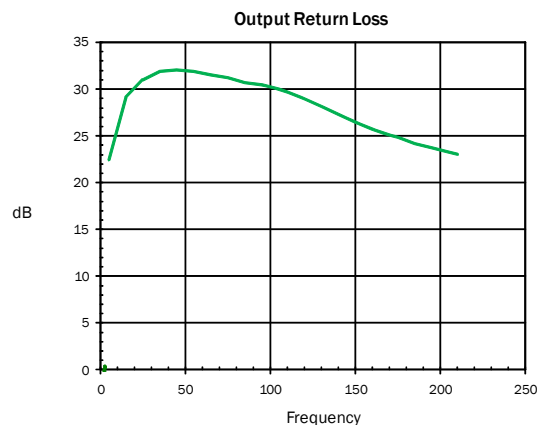
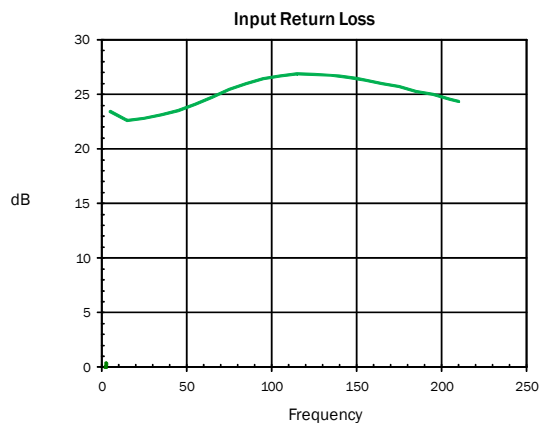


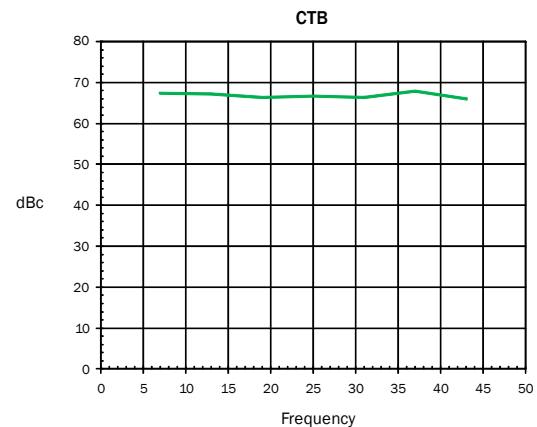
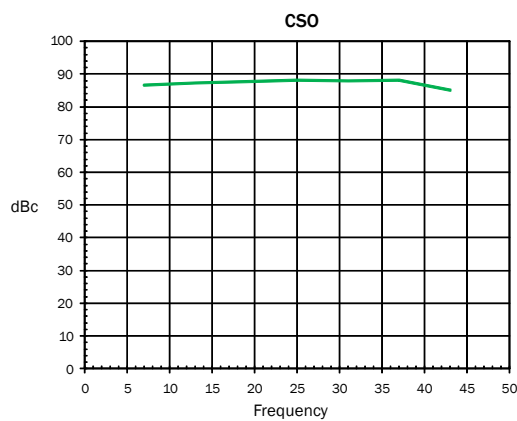
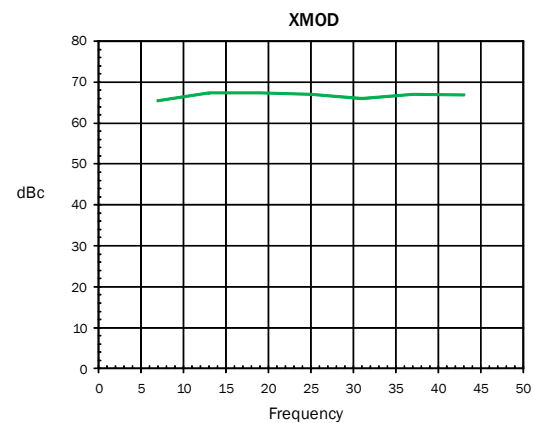
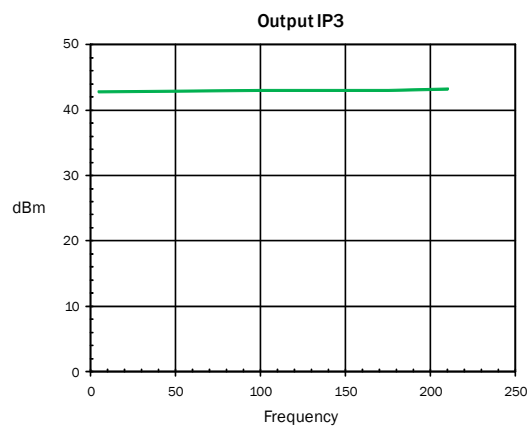
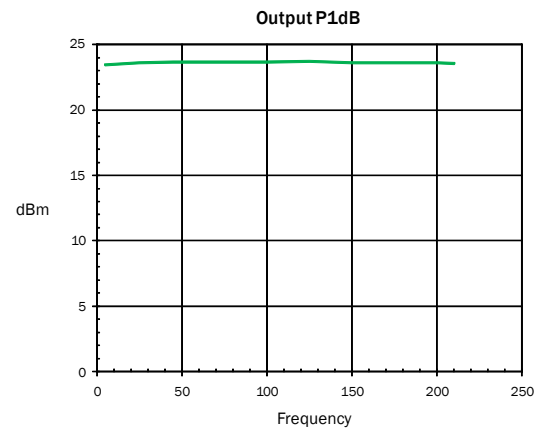
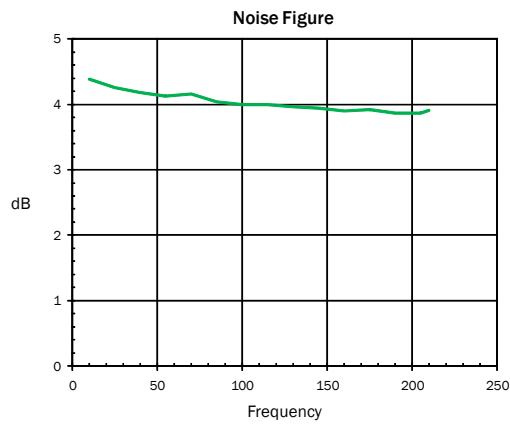
Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

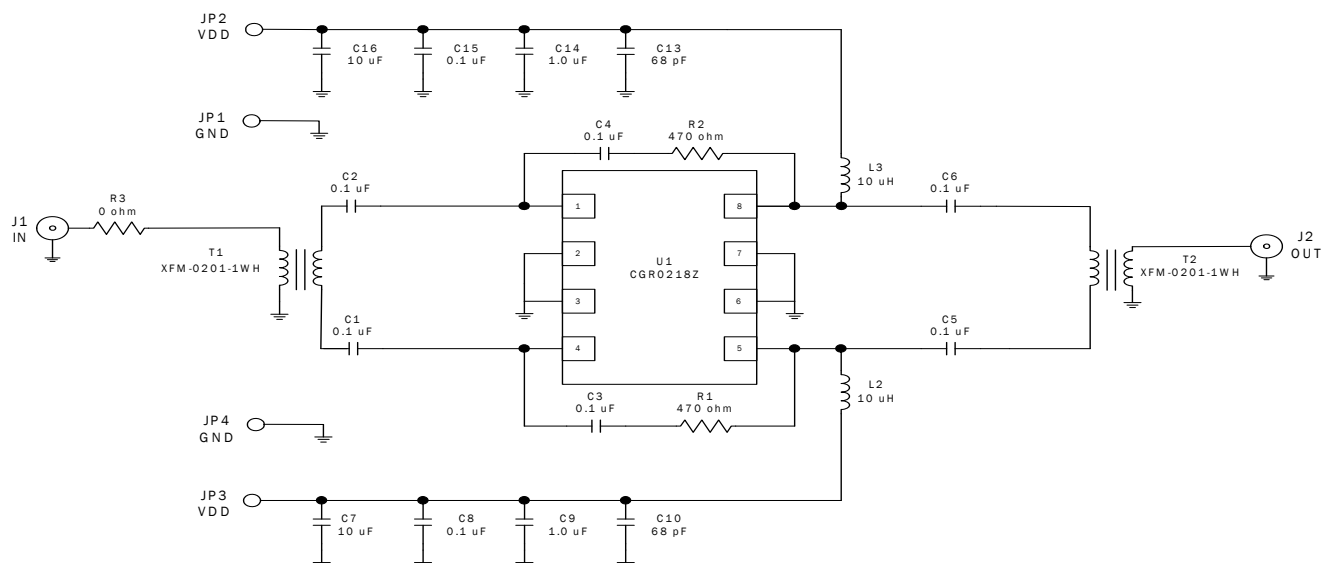
RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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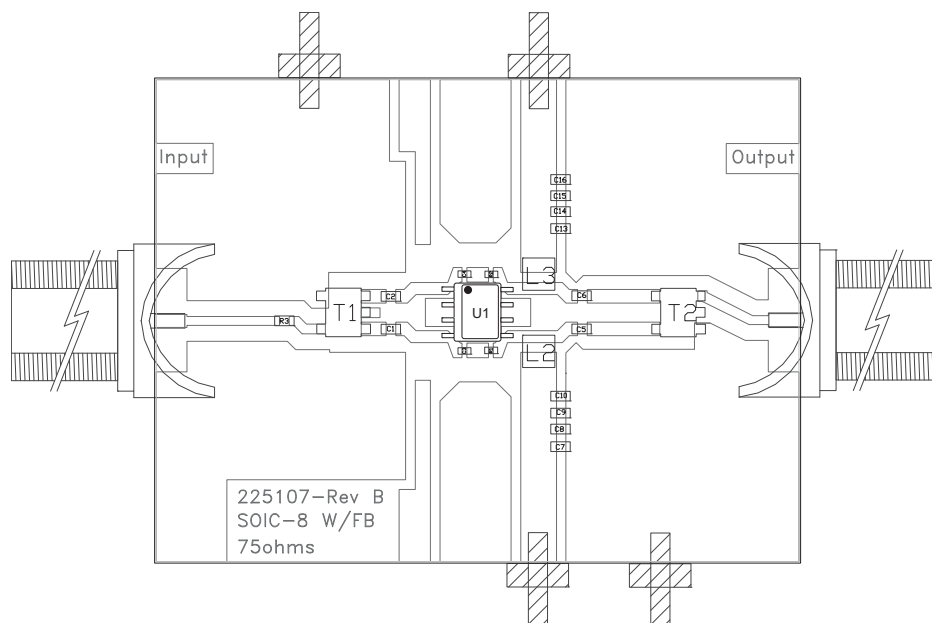




Evaluation Board Schematic



Evaluation Board Layout

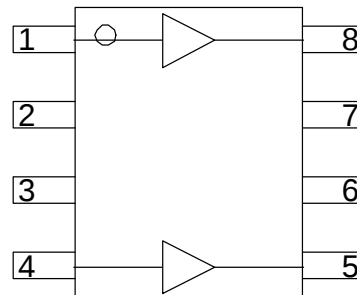


Value	QTY	Location
68pF	2	C10, C13
0.1uF	8	C1, C2, C3, C4, C5, C6, C8, C15
1.0uF	2	C9, C14
10uF	2	C7, C10
0Ω	1	R3
470Ω	2	R1, R2
10uH	2	L2, L3
RFMD™ XFM-0201-1WH	2	T1, T2

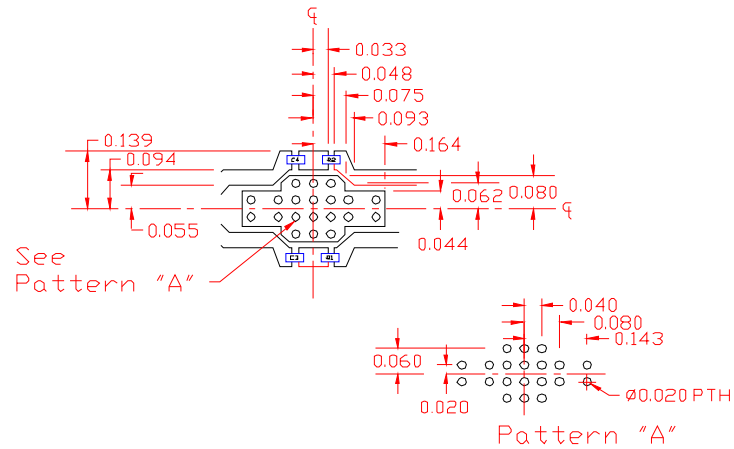
Pin	Function	Description
1	RF IN	RF input pin. External DC blocking capacitor is required.
2, 3, 6, 7	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
4	RF IN	Same as pin 1.
5	RF OUT/VCC	RF output and bias pin (open collector).
8	RF OUT/VCC	Same as pin 5.
EPAD	GND	Exposed area on the bottom side of the package must be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern.

Pin Out

Amplifier Configuration



Suggested Pad Layout

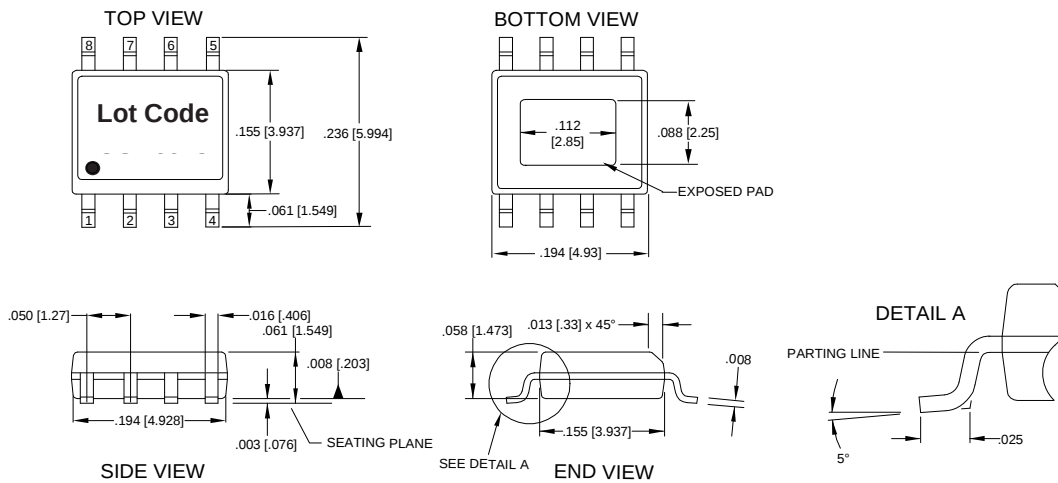


Package Drawing and Marking

Package Type: SOIC-8

Dimensions in inches (millimeters)

Refer to drawing posted at www.rfmd.com for tolerances.



Ordering Information

Part Number	Description	Reel Size (in.)	Devices/Reel
CGR0218ZSB	5pcs Sample Bag	NA	NA
CGR0218ZSQ	25pcs Sample Bag	NA	NA
CGR0218ZSR	Lead Free, RoHS Compliant	7	100
CGR0218ZTR7	Lead Free, RoHS Compliant	7	750
CGR0218ZTR13	Lead Free, RoHS Compliant	13	2500
CGR0218PCBA-410	5MHz to 210MHz Evaluation Board	NA	NA

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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